5 V ECL Quad Differential AND/NAND

Description

The MC10E404/100E404 is a 4-bit differential AND/NAND device. The differential operation of the device makes it ideal for pulse shaping applications where duty cycle skew is critical. Special design techniques were incorporated to minimize the skew between the upper and lower level gate inputs.

Because a negative 2-input NAND function is equivalent to a 2-input OR function, the differential inputs and outputs of the device also allow for its use as a fully differential 2 input OR/NOR function.

The output RISE/FALL times of this device are significantly faster than most other standard ECLinPSTM devices resulting in an increased bandwidth.

The differential inputs have clamp structures which will force the Q output of a gate in an open input condition to go to a LOW state. Thus, inputs of unused gates can be left open and will not affect the operation of the rest of the device. Note that the input clamp will take affect only if both inputs fall 2.5 V below V_{CC} .

The 100 Series contains temperature compensation.

Features

- Differential D and Q
- 700 ps Max. Propagation Delay
- High Frequency Outputs
- PECL Mode Operating Range: $V_{CC} = 4.2 \text{ V to } 5.7 \text{ V}$ with $V_{EE} = 0 \text{ V}$
- NECL Mode Operating Range: $V_{CC} = 0 V$ with $V_{EE} = -4.2 V$ to -5.7 V
- Internal Input 50 kΩ Pulldown Resistors
- ESD Protection: Human Body Model; > 2 kV, Machine Model; > 200 V Charged Device Model; > 2 kV
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level:

$$Pb = 1$$

$$Pb-Free = 3$$

For Additional Information, see Application Note AND8003/D

- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 274 devices
- Pb-Free Packages are Available*



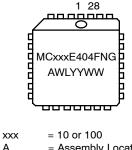
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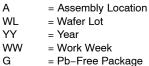
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PLCC-28 FN SUFFIX CASE 776





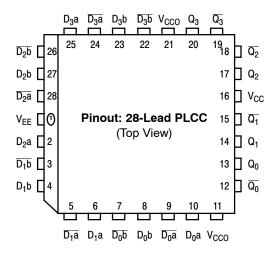


*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



* All V_{CC} and V_{CCO} pins are tied together on the die. Warning: All $V_{CC},\,V_{CCO}$, and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.



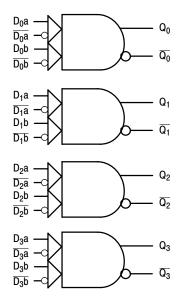


Figure 2. Logic Diagram

Table 1. PIN DESCRIPTION

PIN	FUNCTION
D[0:4], D[0:4]	ECL Differential Data Inputs
Q[0:4], <u>Q</u> [0:4]	ECL Differential Data Outputs
V_{CC} , V_{CCO}	Positive Supply
V _{EE}	Negative Supply

Table 2. One-Column Numbered Table

Da	Db	Q	Da	Db	Q
L	L	L	L	L	L
L	Н	L	L	Н	Н
н	L	L	н	L	н
Н	Н	Н	Н	Н	Н

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V		6 -6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	PLCC-28 PLCC-28	63.5 43.5	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	PLCC-28	22 to 26	°C/W
T _{sol}	Wave Solder Pb Pb-Free			265 265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 4. 10E SERIES PECL DC CHARACTERISTICS V_{CCx} = 5.0 V, V_{EE} = 0.0 V (Note 1)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		106	127		106	127		106	127	mA
V _{OH}	Output HIGH Voltage (Note 2)	3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2)	3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage	3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V _{IL}	Input LOW Voltage	3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
I _{IH}	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5	0.3		0.5	0.25		0.3	0.2		μA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary –0.46 V / +0.06 V. 2. Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V.

Table 5. 10E SERIES NECL DC CHARACTERISTICS $V_{CCx} = 0.0 \text{ V}$; $V_{EE} = -5.0 \text{ V}$ (Note 3)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I_{EE}	Power Supply Current		106	127		106	127		106	127	mA
V _{OH}	Output HIGH Voltage (Note 4)	-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage (Note 4)	-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
V _{IH}	Input HIGH Voltage	-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V _{IL}	Input LOW Voltage	-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
I _{IH}	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5	0.3		0.5	0.065		0.3	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

3. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary –0.46 V / +0.06 V. 4. Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V.

Table 6. 100E SERIES PECL DC CHARACTERISTICS V_{CCx} = 5.0 V; V_{EE} = 0.0 V (Note 5)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		106	127		106	127		122	146	mA
V _{OH}	Output HIGH Voltage (Note 6)	3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 6)	3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V _{IH}	Input HIGH Voltage	3835	3975	4120	3835	3975	4120	3835	3975	4120	mV
V _{IL}	Input LOW Voltage	3190	3355	3525	3190	3355	3525	3190	3355	3525	mV
I _{IH}	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

5. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary –0.46 V / +0.8 V.

6. Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V.

Table 7. 100E SERIES NECL DC CHARACTERISTICS V_{CCx} = 0 V; V_{EE} = -5.0 V (Note 7)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		106	127		106	127		122	146	mA
V _{OH}	Output HIGH Voltage (Note 8)	-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V _{OL}	Output LOW Voltage (Note 8)	-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V _{IH}	Input HIGH Voltage	-1165	-1025	-880	-1165	-1025	-880	-1165	-1025	-880	mV
V _{IL}	Input LOW Voltage	-1810	-1645	-1475	-1810	-1645	-1475	-1810	-1645	-1475	mV
I _{IH}	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

7. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary –0.46 V / +0.8 V. 8. Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V.

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{MAX}	Maximum Toggle Frequency		900			900			900		MHz
t _{PLH}	Propagation Delay to Output										ps
t _{PHL}	Da (Diff)	350	475	650	350	475	650	350	475	650	
	Da (SE)	300	475	700	300	475	700	300	475	700	
	Db (Diff)	375	500	675	375	500	675	375	500	675	
	Db (SE)	325	500	725	325	500	725	325	500	725	
t _{SKEW}	Within-Device Skew (Note 10)		50			50			50		ps
t _{JITTER}	Random Clock Jitter (RMS)		< 1			< 1			< 1		ps
V _{PP} (AC)	Input Voltage Swing (Differential Configuration)	150			150			150			mV
t _r	Rise/Fall Time										
t _f	(20 - 80%)	150		400	150		400	150		400	ps

Table 8. AC CHARACTERISTICS V	$_{CCx}$ = 5.0 V; V_{EE} = 0.0 V or V_{CCx} =	= 0.0 V; V _{EE} = -5.0 V (Note 9)
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NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

9. 10 Series: V_{EE} can vary -0.46 V / +0.06 V. 100 Series: V_{EE} can vary -0.46 V / +0.8 V.

10. Within-device skew is defined as identical transitions on similar paths through a device.

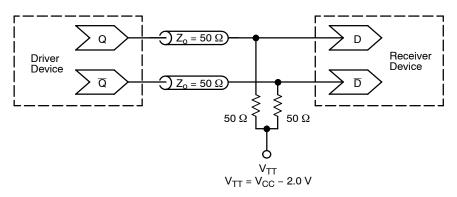


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D - Termination of ECL Logic Devices.)

ORDERING INFORMATION

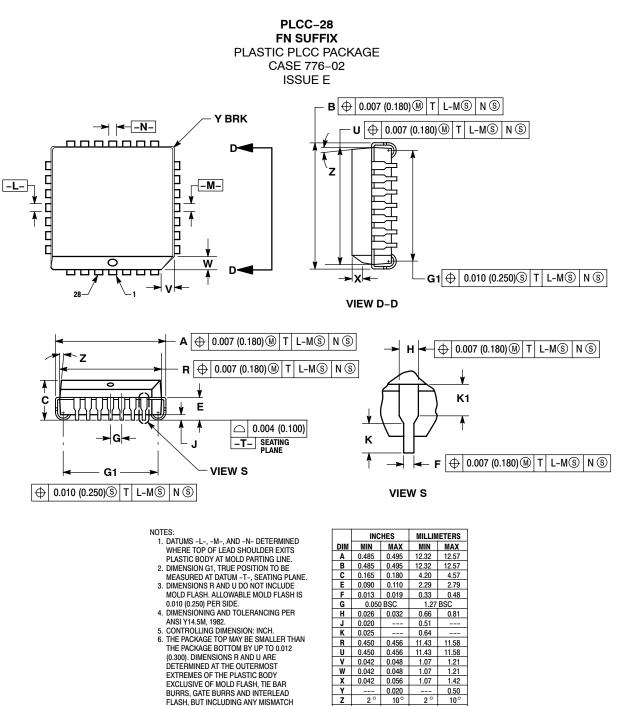
Device	Package	Shipping [†]
MC10E404FN	PLCC-28	37 Units / Rail
MC10E404FNG	PLCC-28 (Pb-Free)	37 Units / Rail
MC10E404FNR2	PLCC-28	500 / Tape & Reel
MC10E404FNR2G	PLCC-28 (Pb-Free)	500 / Tape & Reel
MC100E404FN	PLCC-28	37 Units / Rail
MC100E404FNG	PLCC-28 (Pb-Free)	37 Units / Rail
MC100E404FNR2	PLCC-28	500 / Tape & Reel
MC100E404FNR2G	PLCC-28 (Pb-Free)	500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Resource Reference of Application Notes

AN1405/D	-	ECL Clock Distribution Techniques
AN1406/D	-	Designing with PECL (ECL at +5.0 V)
AN1503/D	-	ECLinPS [™] I/O SPiCE Modeling Kit
AN1504/D	-	Metastability and the ECLinPS Family
AN1568/D	_	Interfacing Between LVDS and ECL
AN1672/D	_	The ECL Translator Guide
AND8001/D	-	Odd Number Counters Design
AND8002/D	_	Marking and Date Codes
AND8020/D	_	Termination of ECL Logic Devices
AND8066/D	_	Interfacing with ECLinPS
AND8090/D	_	AC Characteristics of ECL Devices

PACKAGE DIMENSIONS



2 °

K1 0.040

10 °

G1 0.410 0.430 10.42 10.92

z

BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

7

DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037

(0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

2 °

1.02

10°

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